

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (PCT PROCESS)

2SC2552

SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS.

INDUSTRIAL APPLICATIONS

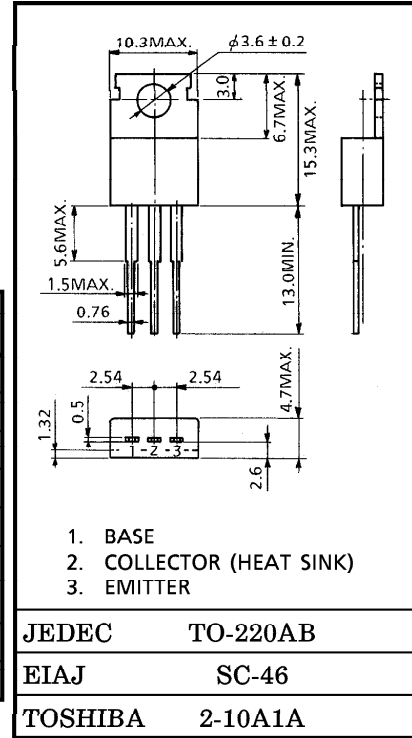
Unit in mm

HIGH SPEED DC-DC CONVERTER APPLICATIONS.

- Excellent Switching Times
: $t_r = 1.0\mu s$ (Max.) $t_f = 1.0\mu s$ (Max.) at $I_C = 0.8A$
- High Collector Breakdown Voltage : $V_{CEO} = 400V$

MAXIMUM RATINGS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	500	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector Current	I_C	2	A
Base Current	I_B	0.5	A
Collector Power Dissipation	P_C	$T_a = 25^\circ C$	1.5
		$T_c = 25^\circ C$	20
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55~150	$^\circ C$



Weight : 1.9g
Mounting kit No. AC75

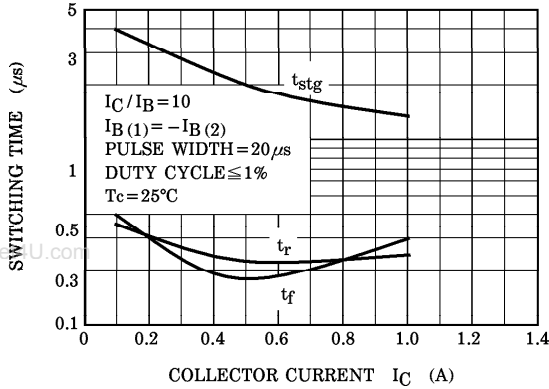
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Collector Cut-off Current	I_{CBO}	$V_{CB} = 400V, I_E = 0$	—	—	100	μA	
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 7V, I_C = 0$	—	—	1	mA	
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1mA, I_E = 0$	500	—	—	V	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	400	—	—	V	
DC Current Gain	$h_{FE(1)}$	$V_{CE} = 5V, I_C = 0.1A$	20	—	—		
	$h_{FE(2)}$	$V_{CE} = 5V, I_C = 1A$	8	—	—		
Saturation Voltage	Collector-Emitter	$V_{CE(sat)}$	$I_C = 1A, I_B = 0.2A$	—	—	V	
	Base-Emitter	$V_{BE(sat)}$	$I_C = 1A, I_B = 0.2A$	—	—		
Switching Time	Turn-on Time	t_r		—	—	1.0	μs
	Storage Time	t_{stg}		—	—	2.5	
	Fall Time	t_f		$I_{B1} = -I_{B2} = 0.08A$ $DUTY\ CYCLE \leq 1\%$ $V_{CC} = 200V$	—	—	

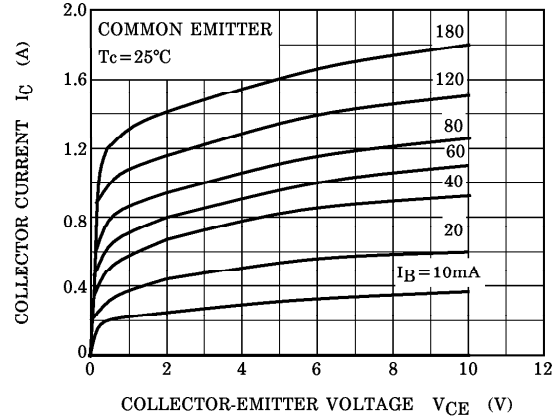
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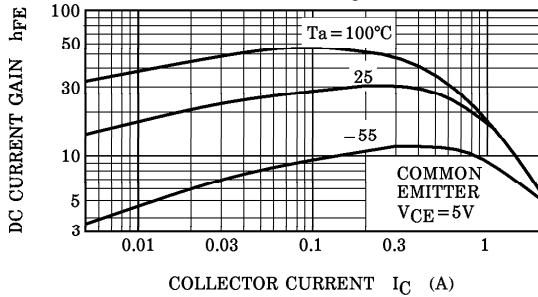
SWITCHING CHARACTERISTICS



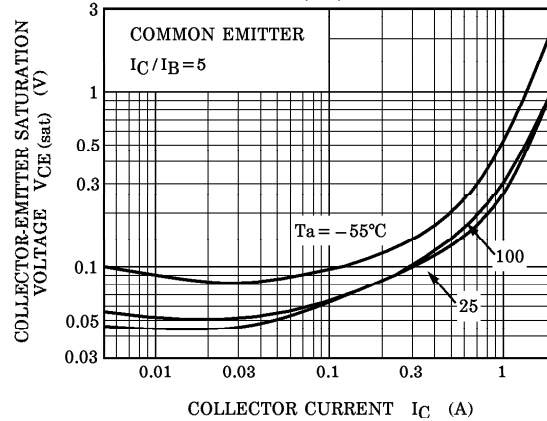
$I_C - V_{CE}$



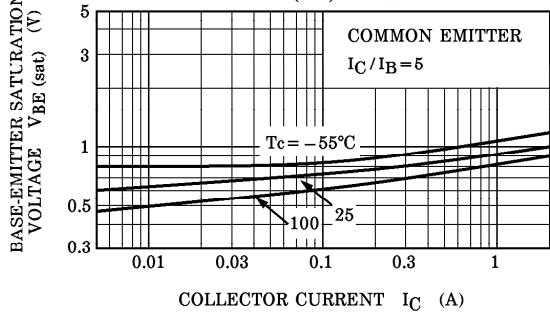
$h_{FE} - I_C$



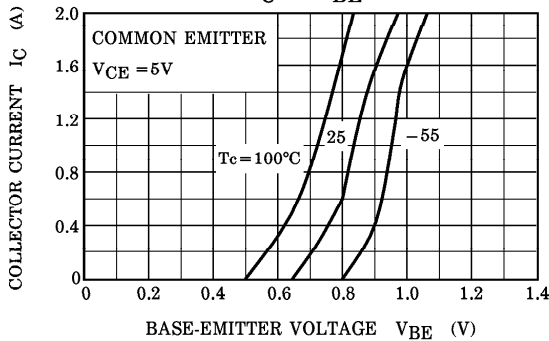
$V_{CE(sat)} - I_C$



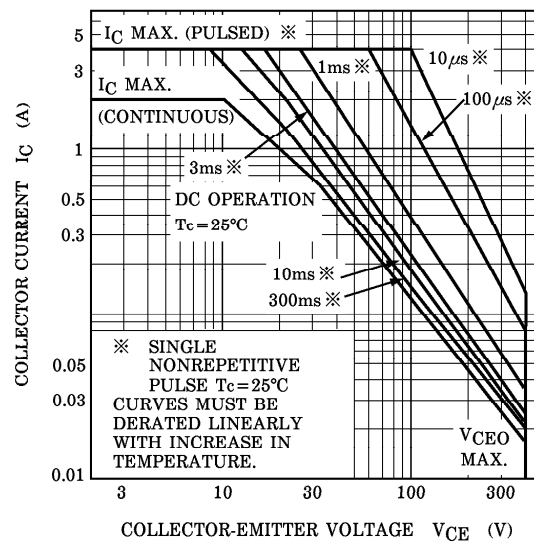
$V_{BE(sat)} - I_C$



$I_C - V_{BE}$



SAFE OPERATING AREA



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